

Detector optimization and physics performance of the CMS Phase-2 Endcap Timing Layer

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My PhD thesis on CDS

The CMS Phase-2 Upgrade

High Luminosity LHC will produce in the CMS experiment:

pileup increase bringing to 140-200 proton-proton collisions per bunch crossing
 Hard to distinguish overlapped collision

• radiation levels reaching $10^{16} n_{eq}/cm^2$ in some subdetectors

To maintain its present performance, CMS will feature important changes with the Phase-2 Upgrade

The MIP Timing Detector (MTD) will provide 4D tracking by adding track time information to separate events overlapped in space but happening at different times



The Endcap Timing Layer

Instrumented with Low Gain Avalanche Diodes + ASIC readout Radiation $\sim 10^{15} n_{eq}/cm^2$

Each endcap is made of two disks covered in silicon sensors on both sides, for a total active area of 7 m² per endcap, hermetic coverage for $1.6 < |\eta| < 3.0$ Time resolution per track <35 ps thanks to single hit resolution <50 ps ETL will contribute in maintaining present CMS performance

ETL requirements: sensors with segmentation of ~1mm², time resolution 30-40 ps, radiation field 1.7×10¹⁵ n_{eq}/cm² An innovative type of silicon detectors matches these requirements: Ultra-Fast Silicon Detectors UFSDs are based on Low Gain Avalanche Diodes, with a moderate internal gain, and optimised for precise timing measurements



MTD will be made of two parts: the Barrel and the Endcap Timing Layer (BTL and ETL)

MTD will improve reconstruction by:

- reconstructing time information for charged particles by combining tracker and MTD measurements
- providing a timing resolution $\sigma_t \sim 30-40 \ ps$ at the start of HL-LHC





Towards the final ETL sensor: from R&D to prototyping

ETL requirements for LGADs considering the best time resolution conditions:

- High hit efficiency and excellent gain uniformity
- Low single pad leakage current to limit power consumption and noise
- High gain and low noise producing >8 fC when new, >5 fC after highest irradiation point
 Excellent time resolution 30-40 ps
- High fill factor: narrow no-gain area (50 µm) and edge width (500 µm at most)
- Long term stability, avoidance of failure modes due to increase of bias with fluence

Breakdown map of pads in an FBK UFSD4 wafer used to compute the sensors yield and uniformity, used to evaluate the quality of a production and the capability of different vendors to produce large sensors with the same Charge collected by two adjacent pads shot with a laser to measure the no-gain distance. The goal is to reach the narrowest no-gain distance while ensuring pad isolation and

Extensive laboratory measurements performed in the Laboratory for Innovative Silicon Sensors in Torino on several LGAD productions to define the characteristics of the perfect sensor for ETL:

Measurements in purple performed by me

- Yield and gain uniformity studies
- No-gain width measurements
- Interpad resistance
- Gain curves and charge collection
- Time resolution: jitter component and total resolution
- Micro-discharges
- Single event burnout studies
- ETL bias granularity

Bias granularity map for FBK UFSD3.2 W19 to maintain a delivered charge of 10-15 fC at 3000 fb⁻¹. Used to define the best gain layer implants for the ETL

Time resolution for sensors with two different gain implants from FBK UFSD4. UFSDs should reach 40 ps below 700 V after irradiation to avoid single event burnout







Results of these and other studies performed within the Torino group have been collected to:

- The sequence of tests needed to fully characterise a UFSD production has been defined and shared with other ETL centres, producing consistent and comparable results
- A subset of these tests has been selected for the Market Survey, considering the importance of the results for ETL and the reduced time at disposal in the MS process

The testing is being finalised and the results on the qualification of the vendors within the Market Survey will be soon made available

The ETL geometry design

As MTD is a new detector, ETL geometry needs to be implemented in the CMS software environment (CMSSW)

The latest ETL version implemented in CMSSW at the moment is ETL v7, included in CMS geometry from scenario D86, based on the engineering drawings from end 2020/beginning 2021



Processes with final states the forward region are significantly improved with CMS Phase-2, particularly with ETL Vector Boson Scattering identified as a case study to verify the improvements brought by MTD







The ETL Navigation Algorithm is used by the reconstruction algorithms to identify the ETL modules compatible with a track



Development of a new efficient algorithm based on the definition of a new dedicated modules order and row-by-row search



MC samples simulated with the latest CMS Phase-2 geometry at 14 TeV and 200 PU for:

- Signal: VBS with $W^{\pm}Zjj \rightarrow \ell^{\pm}\nu\ell^{+}\ell^{-}jj$ final state
- Background: QCD-induced di-boson production with gluon-jets in the final state





QGL performance slightly degrades in the barrel region moving from Phase-1 (JME-22-003) to the high pileup of Phase-2, but significant improvements are noticeable in the forward region with respect to CMS Phase-1 performance

No improvements observed in VBS significance, but the new QGL variable can be used in MVA to increase the sensitivity in rare processes, such as single polarised cross-section of WZ